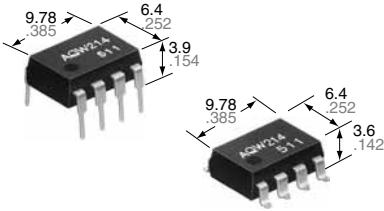
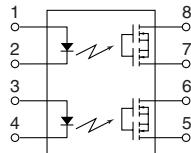


**Compact DIP8-pin type of  
60V to 600V load voltage**

**PhotoMOS®  
GU 2 Form A  
(AQW21○)**



mm inch



**RoHS compliant**

## FEATURES

### 1. Compact 8-pin DIP size

The device comes in a compact (W) 6.4 × (L) 9.78 ×(H) 3.9 mm (W) .252×(L) .385×(H) .154 inch, 8-pin DIP size (through hole terminal type).

### 2. Applicable for 2 Form A use as well as two independent 1 Form A use

### 3. Controls low-level analog signals

PhotoMOS feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.

### 4. High sensitivity and high speed response

Can control max. 0.6 A load current with 5 mA input current. Fast operation speed of typ. 0.65 ms (AQW212).

### 5. Low-level off state leakage current of max. 1 µA

### 6. Wide variation of load voltage 60V to 600V

## TYPICAL APPLICATIONS

- High-speed inspection machines
- Telephones equipment
- Computer

## TYPES

	Output rating*		Package	Part No.			Packing quantity	
				Through hole terminal		Surface-mount terminal		
	Load voltage	Load current		Tube packing style		Tape and reel packing style		
AC/DC dual use			DIP8-pin	AQW212	AQW212A	AQW212AX	AQW212AZ	1 tube contains: 50 pcs. 1 batch contains: 500 pcs.  1,000 pcs.
60V	500 mA	AQW215		AQW215A	AQW215AX	AQW215AZ		
100 V	300 mA	AQW217		AQW217A	AQW217AX	AQW217AZ		
200 V	160 mA	AQW210		AQW210A	AQW210AX	AQW210AZ		
350 V	120 mA	AQW214		AQW214A	AQW214AX	AQW214AZ		
400 V	100 mA	AQW216		AQW216A	AQW216AX	AQW216AZ		

\*Indicate the peak AC and DC values.

Note: The surface mount terminal shape indicator "A" and the packing style indicator "X" or "Z" are not marked on the device.

## RATING

### 1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

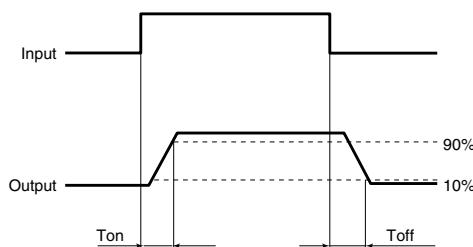
Item	Symbol	AQW212(A)	AQW215(A)	AQW217(A)	AQW210(A)	AQW214(A)	AQW216(A)	Remarks
Input	LED forward current	I <sub>F</sub>			50 mA			
	LED reverse voltage	V <sub>R</sub>			5 V			
	Peak forward current	I <sub>FP</sub>			1 A			f = 100 Hz, Duty factor = 0.1%
	Power dissipation	P <sub>in</sub>			75 mW			
Output	Load voltage (peak AC)	V <sub>L</sub>	60 V	100 V	200 V	350 V	400 V	
	Continuous load current	I <sub>L</sub>	0.50 A (0.60A)	0.30 A (0.35 A)	0.16 A (0.2 A)	0.12 A (0.14 A)	0.10 A (0.13 A)	0.04 A (0.05 A)
	Peak load current	I <sub>peak</sub>	1.0 A	0.9 A	0.48 A	0.36 A	0.3 A	0.12 A
	Power dissipation	P <sub>out</sub>			800 mW			
Total power dissipation		P <sub>T</sub>			850 mW			
I/O isolation voltage		V <sub>iso</sub>			1,500 V AC			Between input and output/between contact sets
Temperature limits	Operating	T <sub>opr</sub>			-40°C to +85°C	-40°F to +185°F		Non-condensing at low temperatures
	Storage	T <sub>stg</sub>			-40°C to +100°C	-40°F to +212°F		

# GU 2 Form A (AQW21○)

## 2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item			Symbol	AQW212(A)	AQW215(A)	AQW217(A)	AQW210(A)	AQW214(A)	AQW216(A)	Condition
Input	LED operate current	Typical	$I_{Fon}$	0.9 mA					$I_L = \text{Max.}$	
		Maximum		3 mA						
	LED turn off current	Minimum	$I_{Foff}$	0.4 mA					$I_L = \text{Max.}$	
		Typical		0.79 mA						
Output	LED dropout voltage	Typical	$V_F$	1.25 V (1.14 V at $I_F = 5 \text{ mA}$ )					$I_F = 50 \text{ mA}$	
		Maximum		1.5 V						
	On resistance	Typical	$R_{on}$	0.83 Ω	2.3 Ω	11 Ω	23 Ω	30 Ω	70 Ω	$I_F = 5 \text{ mA}$
		Maximum		2.5 Ω	4.0 Ω	15 Ω	35 Ω	50 Ω	120 Ω	$I_L = \text{Max.}$ Within 1 s on time
Transfer characteristics	Off state leakage current	Maximum	$I_{Leak}$	1 μA					$I_F = 0 \text{ mA}$ $V_L = \text{Max.}$	
	Turn on time*	Typical	$T_{on}$	0.65 ms	0.60 ms	0.25 ms	0.25 ms	0.31 ms	0.28 ms	$I_F = 5 \text{ mA}$
		Maximum		2 ms	2 ms	1.0 ms	0.5 ms	0.5 ms	0.5 ms	$I_L = \text{Max.}$
	Turn off time*	Typical	$T_{off}$	0.08 ms	0.06 ms	0.05 ms	0.05 ms	0.05 ms	0.04 ms	$I_F = 5 \text{ mA}$
		Maximum		0.2 ms					$I_L = \text{Max.}$	
	I/O capacitance	Typical	$C_{iso}$	0.8 pF					$f = 1 \text{ MHz}$	
		Maximum		1.5 pF					$V_B = 0 \text{ V}$	
	Initial I/C isolation resistance	Minimum	$R_{iso}$	1,000 MΩ					500 V DC	

\*Turn on/Turn off time



## RECOMMENDED OPERATING CONDITIONS

Please obey the following conditions to ensure proper device operation and resetting.

Item	Symbol	Recommended value	Unit
Input LED current	$I_F$	5	mA

### ■ For Dimensions.

### ■ For Schematic and Wiring Diagrams.

### ■ For Cautions for Use.

#### ■ These products are not designed for automotive use.

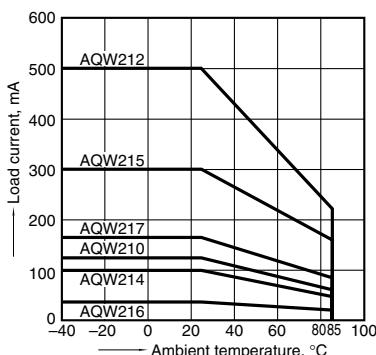
If you are considering to use these products for automotive applications, please contact your local Panasonic Corporation technical representative.

For more information.

## REFERENCE DATA

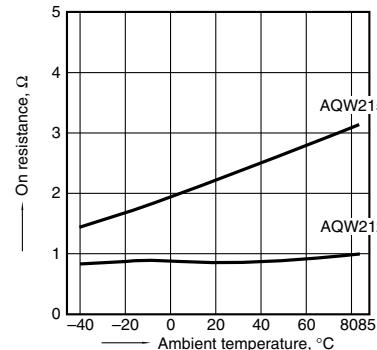
### 1. Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C  
-40°F to +185°F



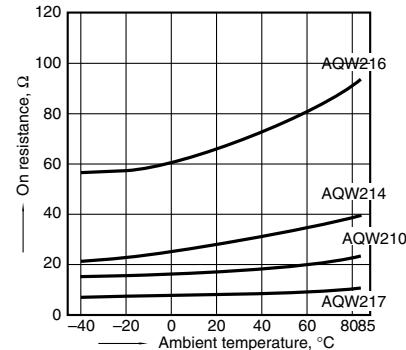
### 2.-1) On resistance vs. ambient temperature characteristics

Measured portion: between terminals 5 and 6, 7 and 8;  
LED current: 5 mA; Load voltage: Max. (DC);  
Continuous load current: Max. (DC)



### 2.-2) On resistance vs. ambient temperature characteristics

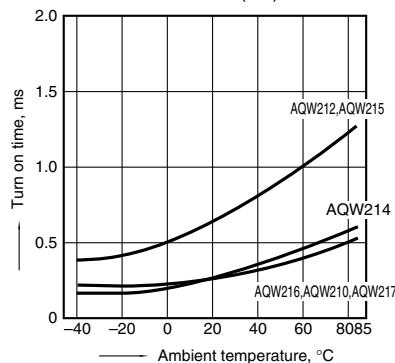
Measured portion: between terminals 5 and 6, 7 and 8;  
LED current: 5 mA; Load voltage: Max. (DC);  
Continuous load current: Max. (DC)



# GU 2 Form A (AQW21○)

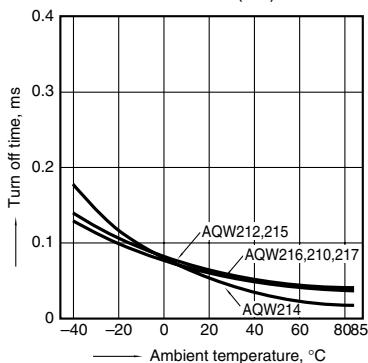
## 3. Turn on time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



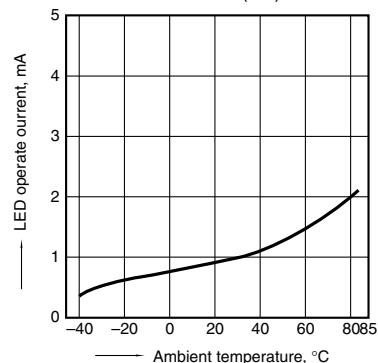
## 4. Turn off time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



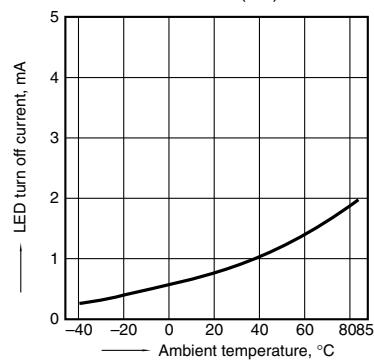
## 5. LED operate current vs. ambient temperature characteristics

Sample: All types; Load voltage: Max. (DC); Continuous load current: Max. (DC)



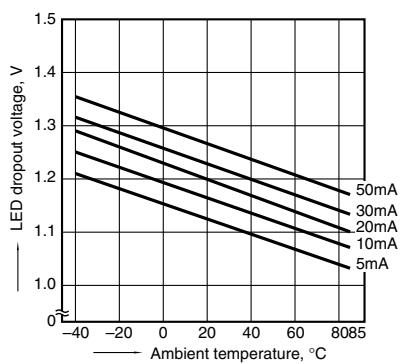
## 6. LED turn off current vs. ambient temperature characteristics

Sample: All types; Load voltage: Max. (DC); Continuous load current: Max. (DC)



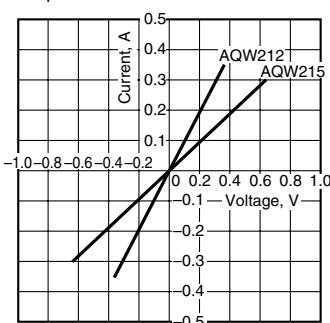
## 7. LED dropout voltage vs. ambient temperature characteristics

Sample: All types; LED current: 5 to 50 mA



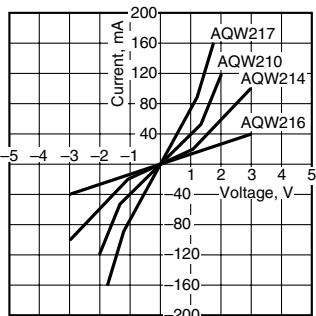
## 8.-1) Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 5 and 6, 7 and 8; Ambient temperature: 25°C 77°F



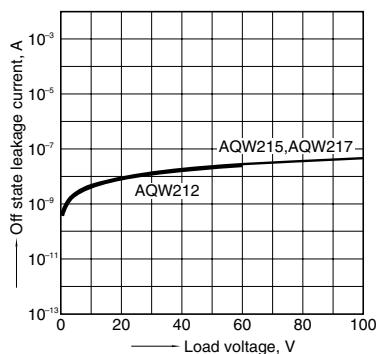
## 8.-2) Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 5 and 6, 7 and 8; Ambient temperature: 25°C 77°F



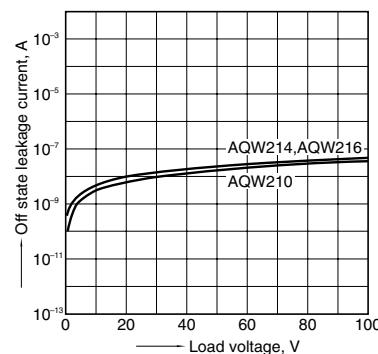
## 9.-1) Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Ambient temperature: 25°C 77°F



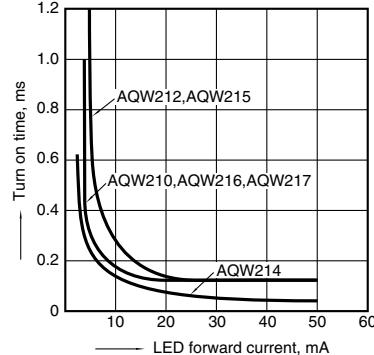
## 9.-2) Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Ambient temperature: 25°C 77°F



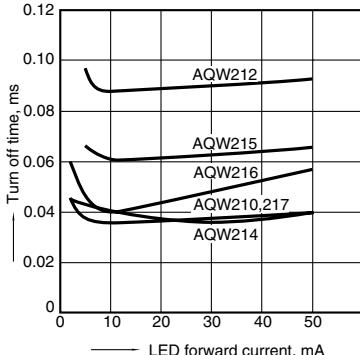
## 10. Turn on time vs. LED forward current characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



## 11. Turn off time vs. LED forward current characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



## 12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Frequency: 1 MHz; Ambient temperature: 25°C 77°F

